

2-input OR Gate

REJ03D0203-0500Z (Previous ADE-205-018C (Z)) Rev.5.00 Feb.02.2004

Description

The HD74UH32 is high speed CMOS two input OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

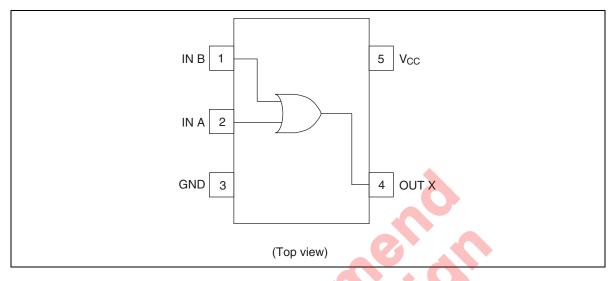
Features

- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC32 Supply voltage range: 2 to 6 V Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74UH32EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)	



Pin Arrangement



Article Indication

Marking Lot number
H 4 A

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	-0.5 to +7.0	V
Input voltage	V _{IN}	–0.5 to V _{CC} +0.5	V
Output voltage	V _{OUT}	–0.5 to V _{CC} +0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	Ι _{ΟΚ}	±20	mA
Output current	I _{OUT}	±25	mA
V _{CC} /GND current	I _{CC} , I _{GND}	±25	mA
Power dissipation	PT	200	mW
Storage temperature	Tstg	-65 to +150	°C



Recommended Operating Conditions

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	Topr	-40 to +85	°C
Input rise/fall time	t _r , t _f	0 to 1000 (V _{CC} = 2.0 V)	ns
		0 to 500 ($V_{CC} = 4.5 V$)	
		0 to 400 ($V_{CC} = 6.0 \text{ V}$)	

Electrical Characteristics

Electrical Characteristics							no l					
		Vcc	Ta =	25°C		Ta = -40 to 85°C						
Item	Symbol	(V)	Min	Тур	Max	Min		Max	Unit	Test Con	ditions	
Input voltage	VIH	2.0	1.5	—	—	1.5		-	V	2		
		4.5	3.15	—	—	3.15		- 6				
		6.0	4.2	—		4.2		-25				
	VIL	2.0		_	0.5	<u> </u>		0.5	V			
		4.5	_	F	1.35	_		1.35				
		6.0	-	$\mathbf{\lambda}$	1.8			1.8				
Output voltage	V _{OH}	2.0	1.9	2.0		1.9		_	V		I _{OH} = −20 μA	
		4.5	4.4	4.5	4	4.4		_				
		6.0	5.9	6.0	F	5.9		_				
		4.5	4.18	4.31	_	4.13		_			$I_{OH} = -2 \text{ mA}$	
		6.0	5.68	5.80	—	5.63		_			I _{OH} = -2.6 mA	
	Vol	2.0		0.0	0.1	—		0.1	V	$V_{\text{IN}} = V_{\text{IL}}$	I _{OL} = 20 μA	
	-	4.5	_	0.0	0.1	—		0.1				
		6.0		0.0	0.1	—		0.1				
		4.5	_	0.17	0.26	_		0.33			$I_{OL} = 2 \text{ mA}$	
		6.0	—	0.18	0.26	_		0.33			I _{OL} = 2.6 mA	
Input current	I _{IN}	6.0	_	_	±0.1	—		±1.0	μΑ	$V_{IN} = V_{CC}$	or GND	
Operating current	Icc	6.0			1.0			10.0		$V_{\rm IN} = V_{\rm CC}$	or GND	



Switching Characteristics

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$

		Ta = 2	25°C			
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Output rise/fall time	t _{TLH} t _{THL}	—	5	10	ns	See Test circuit
Propagation delay time	t _{PLH} t _{PHL}	_	7	15	ns	See Test circuit

 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

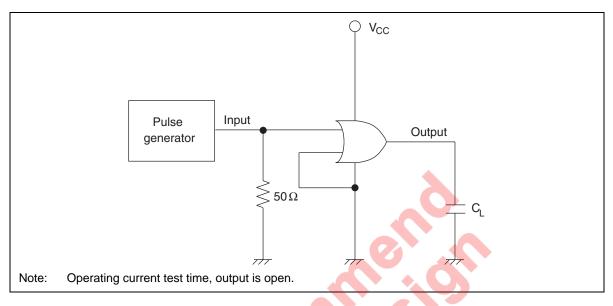
		\textbf{V}_{CC}	Ta = 25°C			Ta = -40 to 85°C			
ltem	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t_{TLH}	2.0	_	50	125	-	155	ns	See Test circuit
	t⊤⊣∟	4.5	_	14	25		31		
		6.0	_	12	21		26		
Propagation delay time	t _{PLH}	2.0	—	48	100	-	125	ns	See Test circuit
	t _{PHL}	4.5	—	12	20	-0	25	-	
		6.0	-	9	17		21	-	
Input capacitance	C _{IN}	-	5	5	10	-	10	pF	
Equivalent capacitance	CPD	4		10		_	_	-	

Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

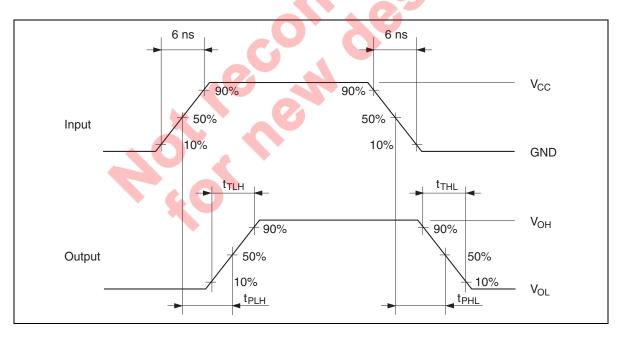
 $I_{CC(opr)} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$



Test Circuit

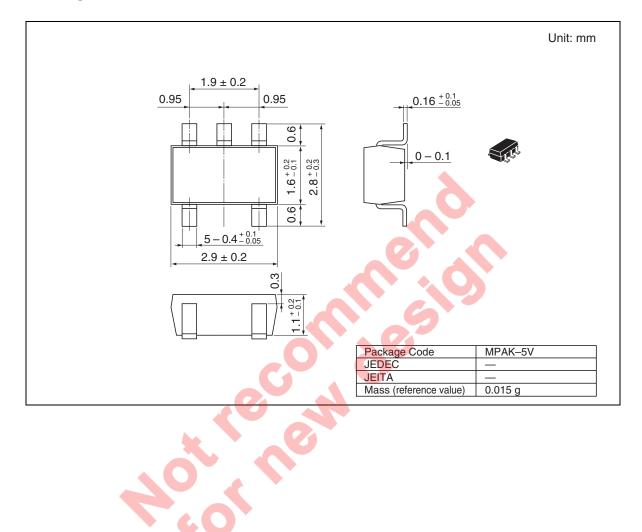


Waveforms





Package Dimensions





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